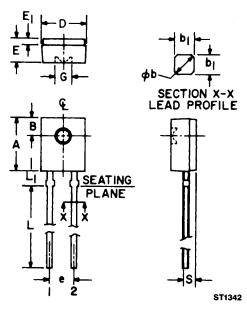


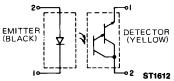
H23B1

PACKAGE DIMENSIONS



SYMBOL	MILLIMETERS		INC	NOTES	
OTHIDOL	MIN.	MAX.	MIN.	MAX.	NOILS
A	5.59	5.80	.220	.228	
В	1.78	NOM.	.070	NOM.	2
® b	.60	.75	.024	.030	1
b ₁	.51	NOM.	.020	NOM.	1
D	4.45	4.70	.175	.185	
E	2.41	2.67	.095	.105	
Ε,	.58	.69	.023	.027	
е	2.41	2.67	.095	.105	3
G	1.98	NOM.	.078	NOM.	
L	12.7		.500	-	
L,	1.40	1.65	.055	.065	
S	.83	.94	.033	.037	3

PACKAGE OUTLINE



NOTES

- TWO LEADS. LEAD CROSS SECTION DIMENSIONS UNCONTROLLED WITHIN 1.27 mm (0.50") OF SEATING PLANE.
- 2. CENTERLINE OF ACTIVE ELEMENT LOCATED WITHIN .25 mm (.010") OF TRUE POSITION.
- 3. AS MEASURED AT THE SEATING PLANE.
- 4. INCH DIMENSIONS DERIVED FROM MILLIMETERS.

DESCRIPTION

The H23B1 is a matched emitter-detector pair which consists of a gallium arsenide infrared emitting diode and a silicon photodarlington. The clear epoxy packaging system is designed to optimize the mechanical resolution, coupling efficiency, cost, and reliability. The devices are marked with a color dot for easy identification of the emitter and detector.

FEATURES

- Good optical to mechanical alignment
- Color dot for easy recognition of LED and phototransistor
- Low cost

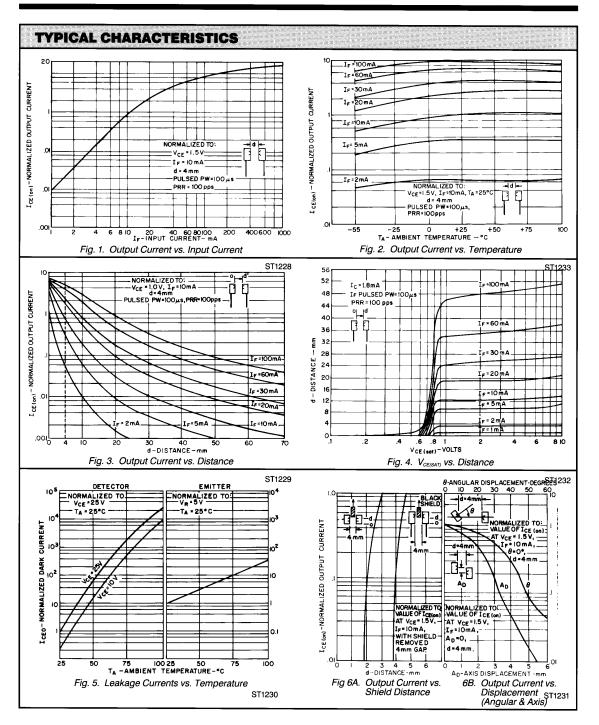


ABSOLUTE MAXIM	IUM RATINGS (T _A = 25°C Unless Otherwise Specified)
Storage Temperature Operating Temperature Soldering: Lead Temperature (Iron	
INPUT DIODE Continuous Forward Currer Reverse Voltage	w)
OUTPUT DARLINGTON Collector-Emitter Voltage . Emitter-Collector Voltage .	

ELECTRICAL CHARACTERISTICS (T _A = 25°C Unless Otherwise Specified)								
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS		
INPUT DIODE								
Forward Voltage	$V_{\scriptscriptstyle F}$	_		1.7	٧	$I_F = 60 \text{ mA}$		
Reverse Leakage Current	I _R			1.0	μA	V _R = 3V		
Reverse Breakdown Voltage	V_{R}	6.0			V	$I_R = 10\mu A$		
OUTPUT DARLINGTON	***				-			
Emitter-Collector Breakdown	BV _{ECO}	7.0		_	٧	$I_{\rm E} = 100 \mu A, Ee = 0$		
Collector-Emitter Breakdown	BV _{CEO}	30		_	V	I _c = 1 mA, Ee=0		
Collector-Emitter Leakage	ICEO	_		100	nA	V _{CE} = 25 V, Ee=0		
COUPLED								
On-State Collector Current	$I_{C(ON)}$	7.5		_	mA	$I_{\scriptscriptstyle F} = 10$ mA, $V_{\scriptscriptstyle CE} = 1.5$ V $^{\scriptscriptstyle (6)}$		
Saturation Voltage	V _{CE(SAT)}	_		1.0	٧	$I_{\rm F} = 10$ mA, $I_{\rm C} = 1.8$ mA $^{(6)}$		
Turn-On Time	t _{on}		8	_	μS	$I_F = 30 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 2.5 \text{K}\Omega$		
Turn-Off Time	t _{off}		50		μS	$I_F = 30 \text{ mA}, V_{CC} = 5 \text{ V}, R_I = 2.5 \text{K}\Omega$		

NOTES

- Derate power dissipation linearly 1.33mW/°C above 25°C.
 Derate power dissipation linearly 2.00mW/°C above 25°C.
- 3. RMA flux is recommended.
- 4. Methanol or Isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/6" (1.6 mm) minimum from housing.
 6. Coupled characteristics are measured at a separation distance of .155" (4 mm) with the lenses of the emitter and detector on a common axis within 0.1mm and parallel within 5°.





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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.